



High-end Power Semiconductor Manufacturer

ZP500A 2000-2800V Standard Rectifier Diode

- High power cycling capability
- Low on-state and switching losses
- Optimized for line frequency rectifiers
- Designed for traction and industrial applications



Average forward current		I_{FAV}		500 A	
Repetitive peak reverse voltage		V_{RRM}		2000 – 2800 V	
V_{RRM}, V	2000	2200	2400	2600	2800
Voltage code	20	22	24	26	28
$T_j, ^\circ C$	-60 – 175				

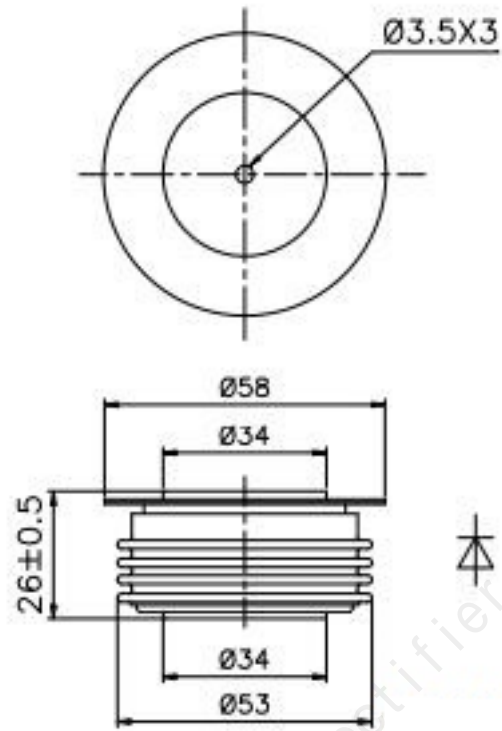
MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions
ON-STATE				
I_{FAV}	Average forward current	A	500	$T_c=100\text{ }^\circ C$; Double side cooled; 180° half-sine wave; 50 Hz
I_{FRMS}	RMS forward current	A	785	$T_c=140\text{ }^\circ C$; Double side cooled; 180° half-sine wave; 50 Hz
I_{FSM}	Surge forward current	kA	11.0 12.0	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ C$ 180° half-sine wave; 50 Hz ($t_p=10\text{ ms}$); single pulse; $V_R=0\text{ V}$;
			11.6 12.6	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ C$ 180° half-sine wave; 60 Hz ($t_p=8.3\text{ ms}$); single pulse; $V_R=0\text{ V}$;
I^2t	Safety factor	$A^2s \cdot 10^3$	605 719	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ C$ 180° half-sine wave; 50 Hz ($t_p=10\text{ ms}$); single pulse; $V_R=0\text{ V}$;
			554 658	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ C$ 180° half-sine wave; 60 Hz ($t_p=8.3\text{ ms}$); single pulse; $V_R=0\text{ V}$;
BLOCKING				
V_{RRM}	Repetitive peak reverse voltages	V	2000–2800	$T_{j\min} < T_j < T_{j\max}$; 180° half-sine wave; 50 Hz;
V_{RSM}	Non-repetitive peak reverse voltages	V	2100–2900	$T_{j\min} < T_j < T_{j\max}$; 180° half-sine wave; 50 Hz; single pulse;
V_R	Reverse continuous voltages	V	$0.75 \cdot V_{RRM}$	$T_j=T_{j\max}$;
THERMAL				
T_{stg}	Storage temperature	$^\circ C$	-60–50	
T_j	Operating junction temperature	$^\circ C$	-60–175	
MECHANICAL				
F	Mounting force	kN	9.0–11.0	
a	Acceleration	m/s^2	50	Device unclamped
			100	Device clamped

CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions	
ON-STATE					
V_{FM}	Peak forward voltage, max	V	1.71	$T_j=25\text{ }^\circ\text{C}; I_{FM}=1570\text{ A}$	
$V_{F(TO)}$	Forward threshold voltage, max	V	1.11	$T_j=T_{j\text{ max}};$	
r_T	Forward slope resistance, max	$m\Omega$	0.700	$0.5\pi I_{FAV} < I_T < 1.5\pi I_{FAV}$	
BLOCKING					
I_{RRM}	Repetitive peak reverse current, max	mA	50	$T_j=T_{j\text{ max}};$ $V_R=V_{RRM}$	
THERMAL					
R_{thjc}	Thermal resistance, junction to case, max	$^\circ\text{C/W}$	0.036	Direct current	Double side cooled
R_{thjc-A}			0.079		Anode side cooled
R_{thjc-K}			0.065		Cathode side cooled
R_{thck}	Thermal resistance, case to heatsink, max	$^\circ\text{C/W}$	0.008	Direct current	
MECHANICAL					
w	Weight, typ	g	180		
D_s	Surface creepage distance	mm (inch)	23.69 (0.933)		
D_a	Air strike distance	mm (inch)	19.10 (0.752)		

OVERALL DIMENSIONS



ZT40

All dimensions in millimeters